## NSN 5961-01-020-4570

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Inclosure Material:
Plastic
Overall Length:
0.705 inches
Terminal Length:
0.381 inches
Overall Height:
0.546 inches
Overall Width:
0.400 inches
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-220ab
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
400.0 repetitive peak off-state voltage and 1.8 on-state voltage, dc
Current Rating Per Characteristic:
8.00 amperes forward current, total rms nanoamperes and 30.00 milliamperes forward current, total rms peak
Maximum Operating Tempurature Per Measurement Point:
109.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnpn
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0